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Lifshitz Transition in Topological Insulators with Second and Third-Neighbor Interactions

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Topological Lifshitz transitions involve many types of topological structures in momentum and frequency-momentum spaces, where the energy band of a topological insulator is calculated taken into account second and third neighbors. A tight-binding model based on the Bernevig-Hughes Zhang (BHZ) approach for quantum wells is used to calculate the energies. The BHZ is characterized by the mass term $M(k) = \Delta - Bk^2$. In the microscopic theory used here, the mass term is $M(k) = \Delta - 2B(2 - cos(k_x a) - cos(k_y a))$ that is modified when second and/or third neighbors are included in the model, as a consequence the range where the material is an insulator is changed.

Introduction

The key word in consideration of Lifshitz transitions is topology. Following original Lifshitz paper [1], Lifshitz transition has been viewed as a change of the topology of the Fermi surface without symmetry breaking The combination of topology of the shape of the Fermi surfaces, Fermi lines and Fermi points together with the topology, which supports the stability of these objects, and also the topology of the interconnections of the objects of different dimensions provide a large number of different types of Lifshitz transitions (some of the are discussed in Refs.[2,3]). This makes the Lifshitz transtions ubiquitous with applications to high energy physics, cosmology, black hole physics and to search for the room-T superconductivity.

The topological insulators (TIs) were first predicted in graphene where spin-orbit interactions were included [4,5]. The quantum spin hall effect generates an energy gap in the bulk system. However, the system has edge helicoidal gapless states with spins moving in opposite directions, with little or no dissipation, which are topologically protected against moderate electronic interactions or nonmagnetic disorder. The edge states are massless Dirac Fermions that cross the whole forbidden gap separating the valence and conduction band. By helicity of edge states we mean that electrons with the same spin can move only in one direction, which is opposite for two spin directions. As a result, the edge states are robust against elastic backscattering, which conserves spin, and the electron transport along edges becomes ballistic, that turn these materials into promising ones for many applications, such as spintronics and quantum devices. These Dirac-like states are protected by time-reversal symmetry (TRS)[6] or by crystal symmetry [7-9].

Understanding the properties of the edge states has been an interesting aspect of TIs theoretical studies [10–14]. It can be done by constructing an appropriate tight binding model Hamiltonian and examining their eigenstates for lattices with boundaries. A very useful model was proposed by Benevig, Hugues e Zhang (BHZ) that is based on Hgte/CdTe quantum wells (QWs). The crucial ingredient of this narrow gap semiconductor structure is the inverted band structure of HgTe. In the HgTe/CdTe QWs, the topological phase is determined by the sign of the Dirac mass M. The gap between the E1 (s-like) and the H1 (p-like) subbands at the Γ point is given by $2|M|$. The only experimentally accessible parameter tuning the Dirac mass from normal ($M > 0$) to inverted ($M < 0$) is the thickness of the HgTe QW. In particular, a topological transition from the normal to the topological insulating phase takes place when the QW thickness is increased above the critical thickness $d_c = 6.3$nm. Bernevig et al [15] predicted samples with such an inverted band structure to be quantum spin Hall insulators with a band gap of tens of meV, which was soon verified experimentally [16]. A peculiar feature in the electronic structure of these states is the existence of so called Lifshitz points, where the change in topology of constant energy contours occurs. By varying the filling of the surface

states, the Lifshitz transitions could, in principle, be induced, with interesting consequences on surface transport.

Tight-Binding Hamiltonian for Z_2 Topological Insulators

The model used to describe the Z_2 topological insulators is constituted by a square lattice, where each site on the network contains two orbitals, where one has odd and the other even parity. The orbital with odd parity has a higher energy than the orbital with even parity. This model is a simplification of the Bernevig-Hughes-Zhang model for quantum wells that have recently attracted much attention in the study of two-dimensional topological insulators with protected helicoidal states of edge.

The Tight-Binding Hamiltonian is given by,

$$H_{\uparrow} = \sum_{i,\sigma} \dot{o}^{\sigma} a^{\dagger}_{i,\sigma} a_{i,\sigma} - \frac{1}{2} \sum_{i,j,\sigma,\sigma'} \left(t_{ij}^{\sigma\sigma'} a^{\dagger}_{i,\sigma} a_{j,\sigma'} + hc \right) \tag{1}$$

where i, j runs over all sites of the lattice, $a^{\dagger}_{i,\sigma}$ ($a_{i,\sigma}$) creates (annihilates) an electron on site i

in orbital σ. σ and σ' stand for s or p, $t^{ss(pp)}$ is a constant defining the hopping in the same orbital. Here t_1 is the nearest neighbor coupling between different orbitals. The t^{ss} and t^{pp} are constants, and the $t^{sp}=\exp(i\theta_{ij})t_1$ ($t^{ps}= \exp(-i\theta_{ij})t_1$) depends on the lattice orientation and θ_{ij} is the angle of the wavevector propagation in the lattice. The Hamiltonian can now be rewritten in the plane wave orbital basis

$$\begin{aligned} H_k = & \sum_k \left[\dot{o}_0^{(s)} - 2t_s \left(\cos(k_x a) + \cos(k_y a) \right) \right] a^{\dagger}_{k,s} a_{k,s} \\ & -2it_1 \left[\sin(k_x a) + i sin(k_y a) \right] a^{\dagger}_{k,s} a_{k,p} + \left[\dot{o}_0^{(p)} - 2t_p \left(\cos(k_x a) + \cos(k_y a) \right) \right] \\ & a^{\dagger}_{k,p} a_{k,p} - 2it_1^{*} \left[-\sin(k_x a) + i sin(k_y a) \right] a^{\dagger}_{k,p} a_{k,s} \end{aligned} \tag{2}$$

and the Hamiltonian can be written as

$$\begin{aligned} H_k = & \sum_k \left[\dot{o}(k) + \Delta - 2B \left(2 - \cos(k_x a) - \cos(k_y a) \right) \right] \\ & a^{\dagger}_{k,s} a_{k,s} + A \left[\sin(k_x a) + i sin(k_y a) \right] a^{\dagger}_{k,s} a_{k,p} \\ & \left[\dot{o}(k) - \Delta + 2B \left(2 - \cos(k_x a) - \cos(k_y a) \right) \right] a^{\dagger}_{k,p} a_{k,p} \\ & -A^{*} \left[-\sin(k_x a) + i sin(k_y a) \right] a^{\dagger}_{k,p} a_{k,s} \end{aligned} \tag{3}$$

where

$$t_p - t_s = B \tag{4}$$

$$\dot{o}_0^{(s)} - \dot{o}_0^{(p)} + 4t_p - 4t_s = 2\Delta, \tag{5}$$

$$A = 2it_1, \tag{6}$$

$$\dot{o}(k) = \frac{\dot{o}_0^{(s)} - \dot{o}_0^{(p)}}{2} - \left(t_s + t_p \right) \left[\cos(k_x a) + \cos(k_y a) \right]. \tag{7}$$

giving the energies

$$E = \sqrt{\left(A(k) \right)^2 + \left(M(k) \right)^2}, \tag{8}$$

with $(A(k))^2 = A^2\ (sin^2(k_x a) + sin^2(k_y a))$ and $M(k) = \Delta - 2B\ (2 - cos(k_x a) - cos(k_y a))$.

The Table 1 below shows the parameters combinationsthat give a zero gap in the energy band. The gap closes in Γ point for $\Delta = 0$, X_1 and X_2 when $\Delta = 4B$, while closes in M when $\Delta = 8B$. There are topological quantum phase transition in these points.

Table 1: The combinations of wave-vector and M resulting in a gapless spectra with the respective Brillouin zone point

BZ	k_x	k_y	Δ
Γ	0	0	0
X1	0	π	4B
X2	π	0	4B
M	π	π	8B

A topological insulator exists when the parameters Δ and B fall in the range, $0 < \Delta/B < 4$ or $4 < \Delta/B < 8$. At $\Delta/B = 4$, which separates the cases of positive and negative quantized spin Hall conductivities. The equation (1) shows the dispersion relation for the topological insulator. The energy increases with increasing the value of the parameters A_1 and B_1. A_1 and B_1 parameter does not change the gap, it shifts the energy everywhere but the Γ point [17].

Tight-Binding Hamiltonian for Z_2 Topological Insulators with Interaction between Nearest-, Second-, and Third-Neighbor

Next, we consider the tight-binding Hamiltonian with interaction between nearest-, second-, and third-neighbor on a square lattice (see Figure 1). The hamiltonian has the same forma as in the previous case, what changes is the structure factos to include the new interactions.

$$\begin{aligned} H_k = & \sum_k \left[\begin{array}{l} \dot{o}_0^{(s)} - 2t_s \left(\cos(k_x a) + \cos(k_y a) \right) - \\ 4t_s^{(2)} \left(\cos(k_x a) \cos(k_y a) \right) - 2t_s^{(3)} \left(\cos(2k_x a) + \cos(2k_y a) \right) \end{array} \right] a^{\dagger}_{k,s} a_{k,s} \\ & + \left(A_1(k) + A_2(k) + A_3(k) \right) a^{\dagger}_{k,s} a_{k,p} + \left(A_1^{*}(k) + A_2^{*}(k) + A_3^{*}(k) \right) a^{\dagger}_{k,p} a_{k,s} \\ & + \left[\begin{array}{l} \dot{o}_0^{(p)} - 2t_p \left(\cos(k_x a) + \cos(k_y a) \right) - 4t_s^{(2)} \left(\cos(k_x a) \cos(k_y a) \right) - 2t_s^{(3)} \\ \left(\cos(2k_x a) + \cos(2k_y a) \right) \end{array} \right] a^{\dagger}_{k,p} a_{k,p}, \end{aligned} \tag{9}$$

where $A_1(k)= 2it_1[sin(k_x a) + i\ sin(k_x a)]$, $A_2(k) = 2i(2)^{1/2}t_2(sin(k_x a)\ cos(k_y a)+isin(k_y a)cos(k_x a))$ and $A_3(k)=2it_3[sin(k_x a)+isin(k_y a)]$. The Hamiltonian can be written as

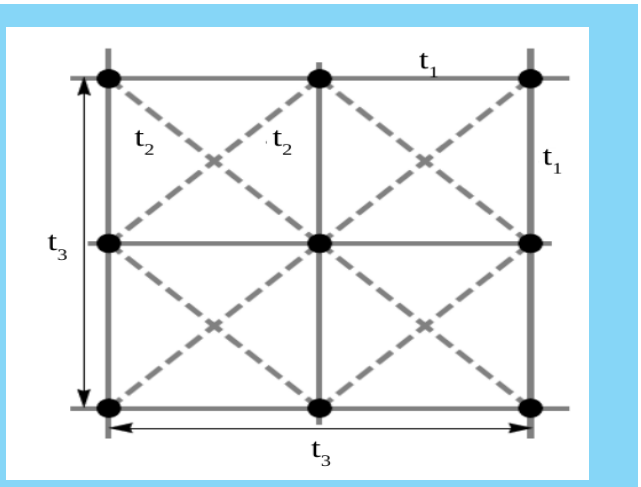

Figure 1: The nearest-, second- andthird- neighbor interactions on a square lattice

$$H_k = \sum_k \begin{bmatrix} \dot{o}(k) + \Delta - 2B\left(2 - \cos(k_x a) - \cos(k_y a)\right) \\ -2B_2\left(2 - 2\cos(k_x a)\cos(k_y a)\right) \end{bmatrix} a^{\dagger}_{k,s} a_{k,s}$$
$$-\left[2B_3\left(2 - \cos(2k_x a) - \cos(2k_y a)\right)\right] a^{\dagger}_{k,s} a_{k,s}$$
$$+\left[\begin{pmatrix} \sin(k_x a) \\ +isin(k_y a) \end{pmatrix} + A_3\left(\sin(2k_x a) + isin(2k_y a)\right)\right] a^{\dagger}_{k,s} a_{k,p}$$
$$+\left[A_2\sqrt{2}\left(\sin(k_x a)\cos(k_y a) + isin(k_y a)\cos(k_x a)\right)\right] a^{\dagger}_{k,s} a_{k,p}$$
$$+\begin{bmatrix} \dot{o}(k) - \Delta + 2B\left(2 - \cos(k_x a) - \cos(k_y a)\right) \\ +2B_2\left(2 - 2\cos(k_x a)\cos(k_y a)\right) \end{bmatrix} a^{\dagger}_{k,p} a_{k,p}$$
$$+2B_3\left(2 - \cos(2k_x a) - \cos(2k_y a)\right) a^{\dagger}_{k,p} a_{k,p}$$
$$+\left[-A^*\left(-\sin(k_x a) + isin(k_y a)\right) - A_3^* \begin{pmatrix} -\sin(2k_x a) \\ +isin(2k_y a) \end{pmatrix}\right] a^{\dagger}_{k,p} a_{k,s}$$
$$+\left[-A_2^*\sqrt{2}\left(-\sin(k_x a)\cos(k_y a) + isin(k_y a)\cos(k_x a)\right)\right] a^{\dagger}_{k,p} a_{k,s} \quad (10)$$

where

$$t_p - t_s = 2B, t_p^{(2)} - t_s^{(2)} = 2B_2, t_p^{(3)} - t_s^{(3)} = 2B_3, \quad (11)$$

$$\dot{o}_0^{(s)} - \dot{o}_0^{(p)} + 4t_p - 4t_s + 4t_p^{(2)} - 4t_s^{(2)} + 4t_p^{(3)} - 4t_s^{(3)} = 2\Delta, \quad (12)$$

$$A = 2it_1, A_2 = 2it_2, A_3 = 2it_3, \quad (13)$$

$$\dot{o}(k) = \frac{\dot{o}_0^{(s)} - \dot{o}_0^{(p)}}{2} - \left(t_s + t_p\right)\left(\cos(k_x a) + \cos(k_y a)\right)$$
$$-2\left(t_s^{(2)} + t_p^{(2)}\right)\left(\cos(k_x a)\cos(k_y a)\right) - \left(t_s^{(3)} + t_p^{(3)}\right)\left(\cos(k_x a) + \cos(k_y a)\right), \quad (14)$$

giving the energies

$$E = \sqrt{\Omega^2 + (\Delta - D)^2}, \quad (15)$$

with $D = 2B(2 - cos(k_x a) - cos(k_y a)) + 2B_2(2 - 2cos(k_x a) cos(k_y a)) + 2B_3(2 - cos(2k_x a) - cos(2k_y a))$ and

$$\Omega^2 = A^2\left(\sin^2(k_x a) + \sin^2(k_y a)\right) + 2AA_2 \begin{pmatrix} \sin^2(k_x a)\cos(k_y a) \\ +\sin^2(k_y a)\cos(k_x a) \end{pmatrix}$$
$$+A_3^2\left(\sin^2(2k_x a) + \sin^2(2k_y a)\right) + 2AA_3 \begin{pmatrix} \sin(k_x a)\sin(2k_x a) \\ +\sin(k_y a)\sin(2k_y a) \end{pmatrix}$$
$$+A_2^2\left(\sin^2(k_x a)\cos^2(k_y a) + \sin^2(k_y a)\cos^2(k_x a)\right)$$
$$2A_2A_3\left(\sin(2k_x a)\sin(k_x a)\cos(k_y a) + \sin(2k_y a)\sin(k_y a)\cos(k_x a)\right). \quad (16)$$

As in the case for next-neighbor the spectra becomes gapless for the parameters show in Table 2.

Table 2: The combinations of wave-vector and Δ resulting in a gapless spectra with the respective Brillouin zone points. Now considering second- and third-neighbors

BZ	k_x	k_y	Δ
Γ	0	0	$-4(B_2 + B_3)$
X1	0	π	$4(B + B_2 - B_3)$
X2	π	0	$4(B + B_2 - B_3)$
M	π	π	$8B - 4(B_2 + B_3)$

The new transitions occurs for $\Delta = -4(B_2 + B_3)$, $\Delta = 4(B + B_2 - B_3)$, and $\Delta = 8B - 4(B_2 + B_3)$.

Lifshitz Transition in Topological Insulator

In Figure 2 the dispersion relation for the topological insulator is shown in a contour plot for four different values of the inter-orbital hopping. The energy increases from blue to red. As we have chosen Δ = 2.0, A_1 = 1.0, B_1 = 1.0, A_2 = 0.2, B_2 = 0.2 and B_3 = 0.04, the gap closes only for the Γ point. The increase in the A_3 parameter does not change the gap, it shifts the energy everywhere but the Γ point. In Figure 3 the A_3 parameter is fixed to show the contour plot for different values of the parameter B_3 and Δ = 2.0. For B_3 = 0 the gap closes for point Γ. The energies increases with B_3 (from blue to red) but in a different way of Figure 1. In Figure 4 we fixed the hopping parameters and changed Δ to show the energy contour plot of the dispersion relation. The band energy changes significantly as we increase Δ and the zero gap depends on the hopping parameters. As compared with the first neighbors case, the one with second and third neighbors gives much more possibilities for the zero gap to exist. We can also note a Lifshitz transition along $X_1 - \Gamma - X_2$. Due to the effect of second and third neighbors on the topological insulator.

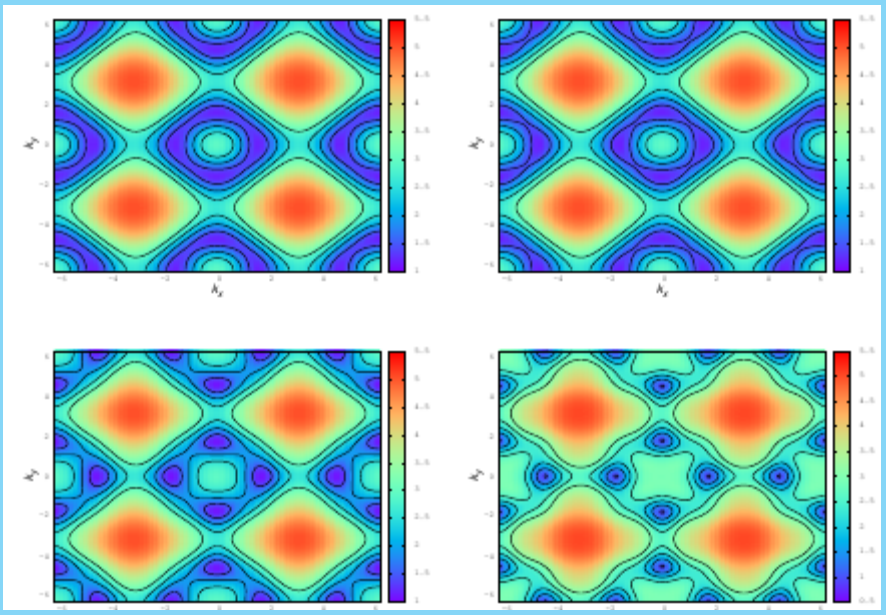

Figure 2: The dispersion relation for Δ = 2.0, B = 1.0, B_2 = 0.20, A_2 = 0.2, B_3 = 0.04 and four different values of A_3. (a) A_3 = 0.05, (b) A_3 = 0.10, (c) A_3 = 0.50 and (d) A_3 = 1.00. The energies increase from blue to red

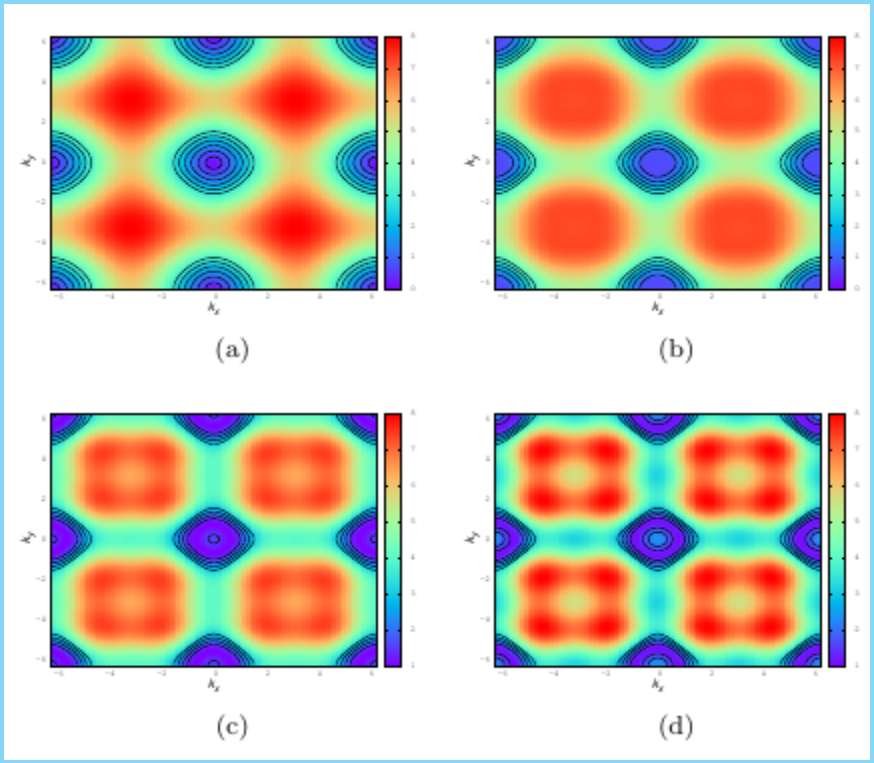

Figure 3: The dispersion relation for Δ = 0.0, B = 1.0, A = 1.0, A_2 = 0.20, A_3 = 0.20 and four different values of B_3. (a) B_3 = 0.00, (b) B_3 = 0.20, (c) B_3 = 0.40 and (d) B_3 = 0.60. The energies increase from blue to red

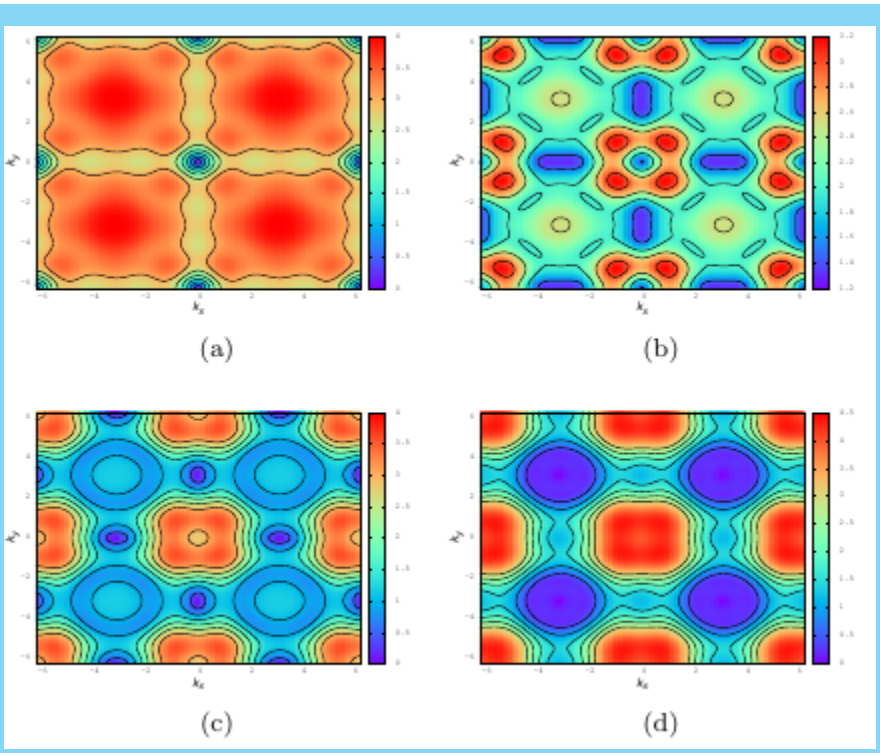

Figure 4: The dispersion relation for different values of Δ, for A1 = 1.50, B1 = 0.50, A2 = 0.90, A3= 0.63, and B3 = 0.02. (a) Δ = -0.48, (b) Δ = 1.00, (c) Δ = 2.32 and (d) Δ = 3.50. The energy increases from blue to red

Conclusion

We have theoretically studied the effect of second and third neighbors on the topological insulator using a tight- binding model. It has been found that the energy band of the Z_2 topological can change drastically depending on the hopping parameters of the second and third neighbors. The emergent singularities in the transition are important for the construction of superconductors with a better transition temperature. The effects of Lifshitz transition are important in different areas of physics.

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